

**Amendments to the Claims:**

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An electro-optical device, comprising:

an active matrix substrate having on the same plane a plurality of scanning lines, a plurality of signal lines provided to intersect the scanning lines, a plurality of pixel electrodes provided at the intersection portions of the scanning lines and the signal lines, and a peripheral driving circuit to matrix drive the pixel ~~electrodes~~; electrodes, the peripheral driving circuit including thin film transistors each having a channel region;

a counter substrate comprising:

a common electrode facing the pixel electrodes of the active matrix,

and

a light shielding film;

a seal that forms a sealed region between the active matrix substrate and the counter substrate, the peripheral driving circuit being disposed at least partially within the sealed region; and

a liquid crystal layer disposed in the sealed region between the active matrix substrate and the counter substrate,

wherein the common electrode and the light shielding film are in a non-overlapping arrangement with at least one of the peripheral driving circuit and wiring lines for supplying signals to the peripheral driving circuit in plan view.

2. (Currently Amended) An electro-optical device, comprising:

an active matrix substrate having on the same plane a plurality of scanning lines, a plurality of signal lines provided to intersect the scanning lines, a plurality of pixel electrodes provided at the intersection portions of the scanning lines and the signal lines, and

a peripheral driving circuit to matrix drive the pixel ~~electrodes~~; electrodes, the peripheral driving circuit including thin film transistors each having a channel region;

a counter comprising:

a common electrode covering ~~an entire~~ a surface of the counter substrate, the common electrode facing the pixel electrodes of the active matrix, and

a light shielding film;

a seal that forms a sealed region between the active matrix substrate and the counter substrate, the peripheral driving circuit being disposed at least partially within the sealed region; and

a liquid crystal layer disposed in the sealed portion between the active matrix substrate and the counter substrate,

wherein the counter substrate and the light shielding film are in a non-overlapping arrangement with at least one of the peripheral driving circuit and wiring lines for supplying signals to the peripheral driving circuit in plan view.

3. (Previously Presented) The electro-optical device according to claim 1, wherein the peripheral driving circuit comprises thin film transistors having channel regions made of single crystal silicon.

4. (Previously Presented) The electro-optical device according to claim 1, wherein a frequency of at least one of the signals supplied to the peripheral driving circuit is equal to or more than 10 MHz.

5. (Previously Presented) The electro-optical device according to claim 1, wherein the peripheral driving circuit comprises at least one of a data line driving circuit and a sample hold circuit, and the wiring lines comprise at least one of clock signal lines, image signal selecting lines, and image signal lines.

6. (Currently Amended) A method of manufacturing an electro-optical device, comprising:

forming a plurality of pixel electrodes and a peripheral driving circuit to matrix drive the plurality of pixel electrodes on one surface of an active matrix ~~substrate~~; substrate, the peripheral driving circuit including thin film transistors each having a channel region;

forming a common electrode and a light shielding film ~~over an entire~~ on a surface of a counter substrate;

arranging the common electrode and the light shielding film of the counter substrate in a non-overlapping arrangement with at least one of the peripheral driving circuit and wiring lines for supplying signals to the peripheral driving circuit in plan view;

bonding the active matrix substrate to the counter substrate with a predetermined gap between the active matrix substrate and the counter substrate using a sealing material to form a sealed region, the peripheral driving circuit being disposed partially within the sealed region, and the common electrode facing the pixel electrodes of the active matrix; and

forming a liquid crystal layer by injecting liquid crystal into the sealed region formed by the active matrix substrate, the counter substrate, and the sealing material.

7. (Original) An electronic apparatus, comprising:

the electro-optical device according to claim 1.